

5SDD 31H6000

Old part no. DV 889-3300-60

High Voltage Diode

Properties

- Industry standard housing
- Suitable for parallel operation
- High operating temperature
- Low forward voltage drop

Key Parameters

V_{RRM}	=	6 000	V
I_{FAVm}	=	3 201	A
I_{FSM}	=	40 000	A
V_{TO}	=	0.944	V
r_T	=	0.166	mΩ

Applications

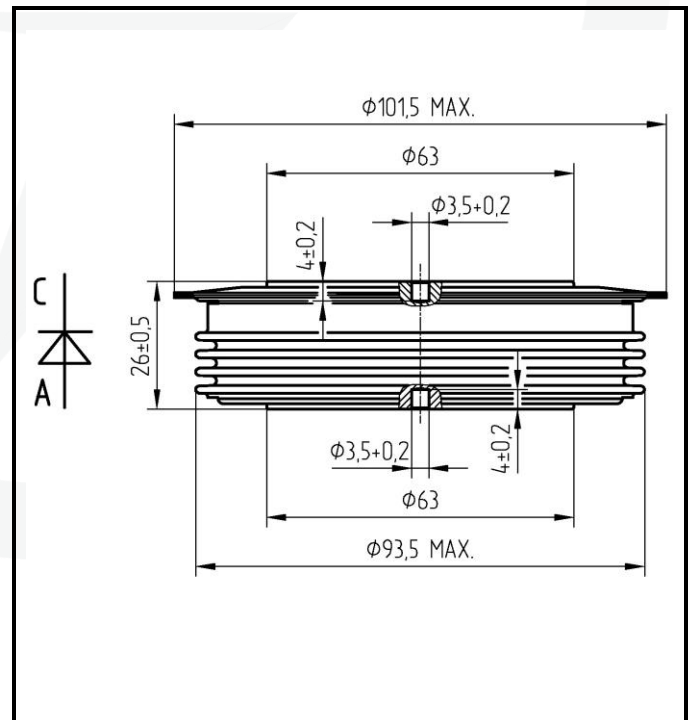
- Rectifier bridges

Types

	V_{RRM}
5SDD 31H6000	6 000 V
Conditions: $T_j = -40 \div 150 \text{ }^\circ\text{C}$, half sine waveform, $f = 50 \text{ Hz}$	

F_m	Mounting force	50 ± 5 kN
m	Weight	0.9 kg
D_s	Surface creepage distance	40 mm
D_a	Air strike distance	20 mm

Mechanical Data



Maximum Ratings		Maximum Limits	Unit	
V_{RRM}	Repetitive peak reverse voltage $T_j = -40 \div 150 \text{ }^\circ\text{C}$	6 000	V	
I_{FAVm}	Average forward current $T_c = 85 \text{ }^\circ\text{C}$	3 201	A	
I_{FRMS}	RMS forward current $T_c = 85 \text{ }^\circ\text{C}$	5 028	A	
I_{RRM}	Repetitive reverse current $V_R = V_{RRM}$	120	mA	
I_{FSM}	Non repetitive peak surge current $V_R = 0 \text{ V, half sine pulse}$	$t_p = 8.3 \text{ ms}$	42 700	A
		$t_p = 10 \text{ ms}$	40 000	A
I^2t	Limiting load integral $V_R = 0 \text{ V, half sine pulse}$	$t_p = 8.3 \text{ ms}$	7 577 200	A²s
		$t_p = 10 \text{ ms}$	8 000 000	A²s
$T_{jmin} - T_{jmax}$	Operating temperature range	-40 \div 150	$^\circ\text{C}$	
T_{STG}	Storage temperature range	-40 \div 150	$^\circ\text{C}$	

Unless otherwise specified $T_j = 150 \text{ }^\circ\text{C}$

Characteristics		Value			Unit
		<i>min</i>	<i>typ</i>	<i>max</i>	
$V_{TO} r_T$	Threshold voltage			0.944	V
	Forward slope resistance $I_{F1} = 4\ 869 \text{ A, } I_{F2} = 14\ 608 \text{ A}$			0.166	m\square
V_{FM}	Maximum forward voltage $I_{FM} = 4\ 000 \text{ A}$			1.600	V
Q_{rr}	Recovered charge $V_R = 100 \text{ V, } I_{FM} = 2000 \text{ A, } di/dt = -30 \text{ A}/\mu\text{s}$		6 500		$\mu\text{C}\square$

Unless otherwise specified $T_j = 150 \text{ }^\circ\text{C}$

Thermal Parameters			Value	Unit
R_{thjc}	Thermal resistance junction to case	double side cooling	8.0	K/kW
		anode side cooling	14.5	
		cathode side cooling	18.0	
R_{thch}	Thermal resistance case to heatsink	double side cooling	2.5	K/kW
		single side cooling	5.0	

Transient Thermal Impedance

Analytical function for transient thermal impedance

$$Z_{thjc} = \sum_{i=1}^4 R_i (1 - \exp(-t / \tau_i))$$

Conditions:

$F_m = 50 \pm 5$ kN, Double side cooled

Correction for periodic waveforms

180° sine:	1.0 K/kW
120° sine:	1.5 K/kW
60° sine:	2.5 K/kW
180° rectangular:	0.9 K/kW
120° rectangular:	1.5 K/kW
60° rectangular:	2.5 K/kW

i	1	2	3	4
τ_i (s)	0.4406	0.1045	0.0092	0.0022
R_i (K/kW)	4.533	2.255	0.868	0.345

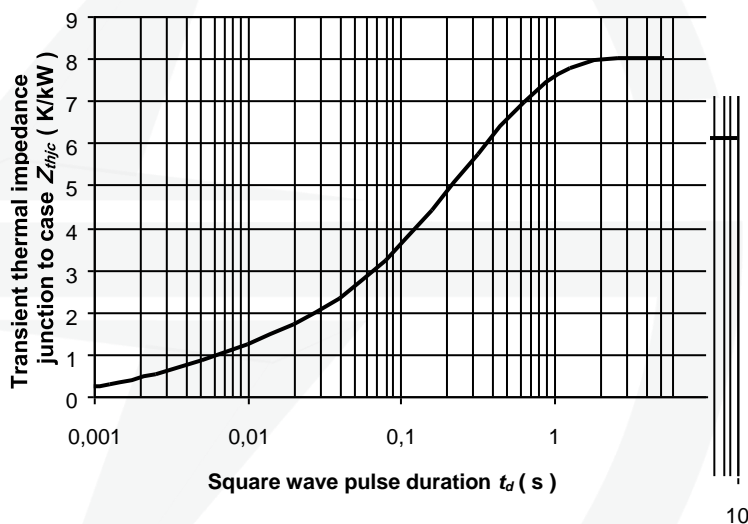


Fig. 2 Dependence transient thermal impedance junction to case on square pulse

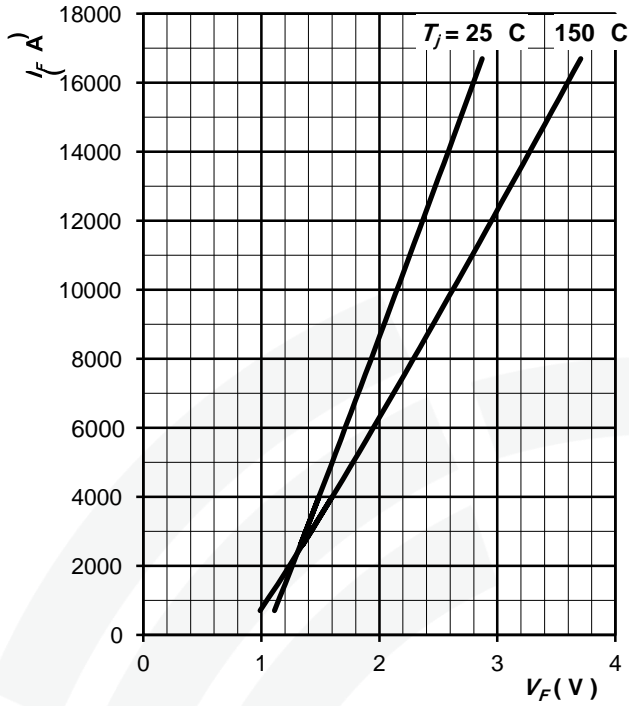


Fig. 3 Maximum forward voltage drop characteristics

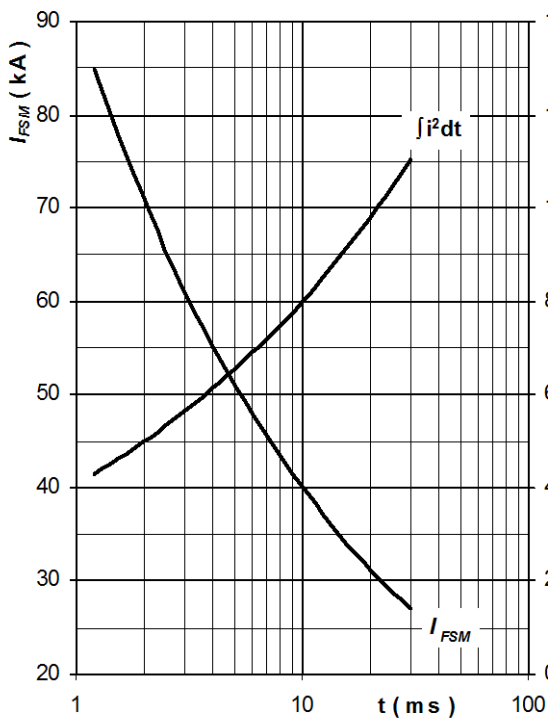


Fig. 4 Surge forward current vs. pulse length, half sine wave, single pulse, $V_R = 0\text{ V}$, $T_j = T_{jmax}$

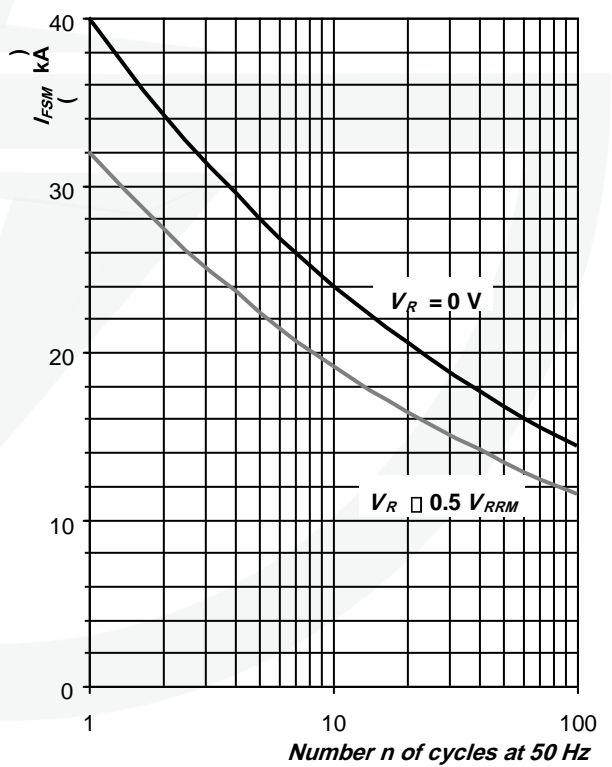


Fig. 5 Surge forward current vs. number of pulses, half sine wave, $T_j = T_{jmax}$

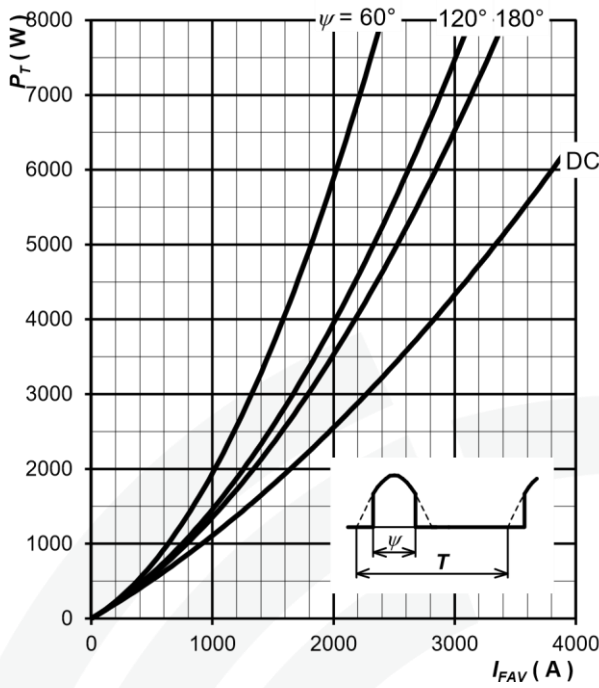


Fig. 6 Forward power loss vs. average forward current, sine waveform, $f = 50 \text{ Hz}$, $T = 1/f$

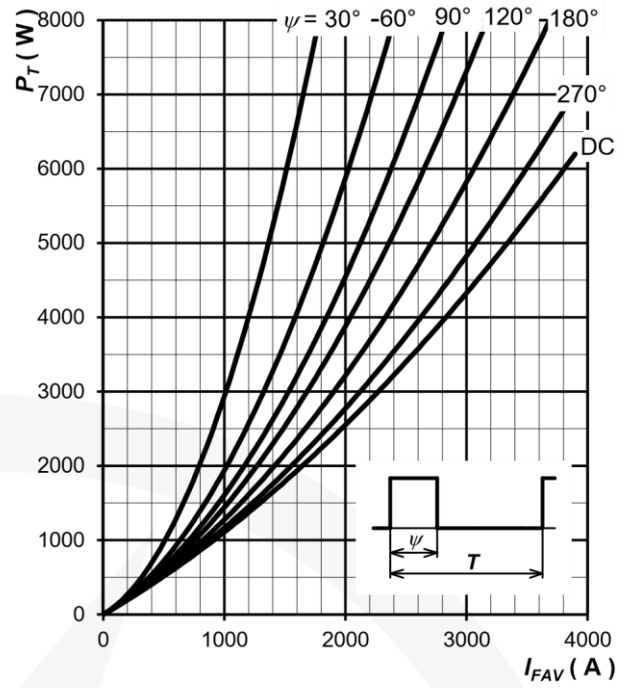


Fig. 7 Forward power loss vs. average forward current, square waveform, $f = 50 \text{ Hz}$, $T = 1/f$

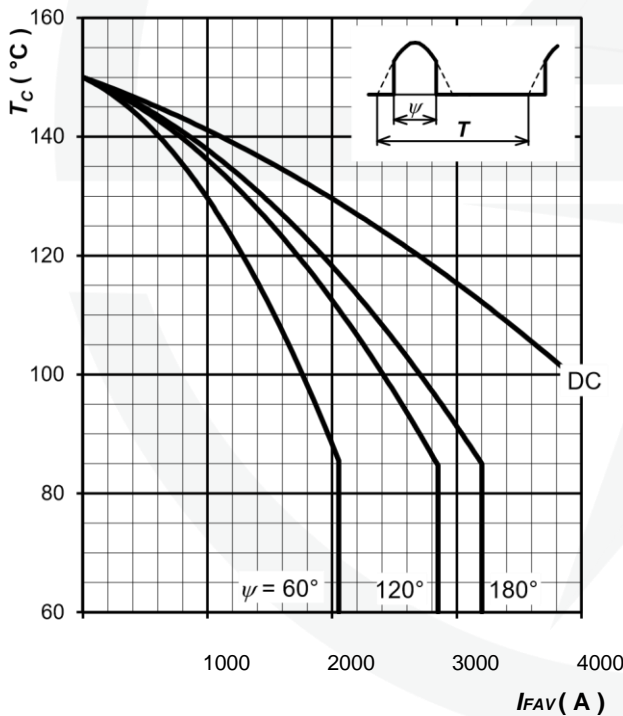


Fig. 8 Max. case temperature vs. aver. forward current, sine waveform, $f = 50 \text{ Hz}$, $T = 1/f$

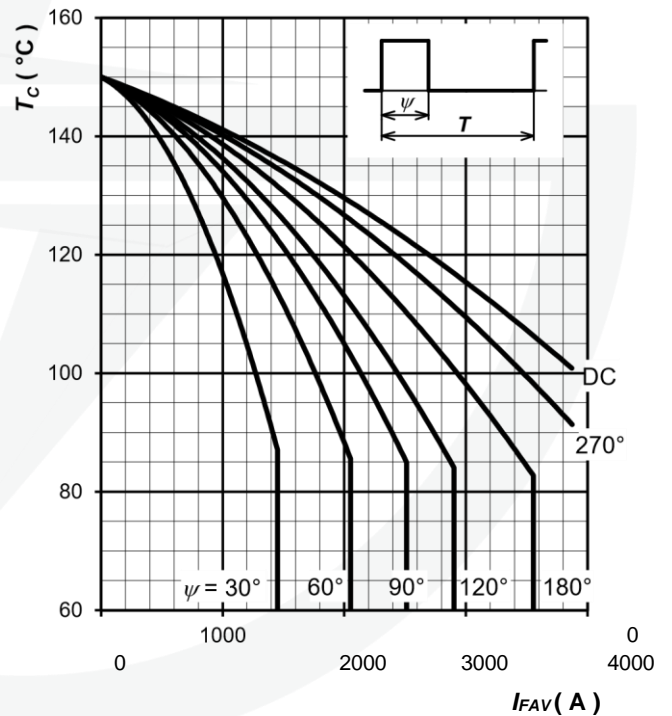


Fig. 9 Max. case temperature vs. aver. forward current, square waveform, $f = 50 \text{ Hz}$, $T = 1/f$